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View Online at https://aerobasegroup.com/nsn/5961-01-171-6432 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.350 inches **End Application:** 6130-01-177-4184 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 18876-10183541-002 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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